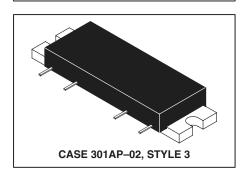
The RF Line UMTS Band RF Linear LDMOS Amplifier

Designed for Class AB amplifier applications in 50 ohm systems operating in the UMTS frequency band. A silicon FET design provides outstanding linearity and gain. In addition, the excellent group delay and phase linearity characteristics are ideal for digital modulation systems.

- Typical W–CDMA Performance for $V_{DD}=28$ Volts, $V_{bias}=8$ Volts, $I_{DQ}=550$ mA, Channel Bandwidth = 3.84 MHz, Adjacent Channels at \pm 5 MHz, ACPR Measured in 3.84 MHz Bandwidth. Peak/Avg. = 8.5 dB @ 0.01% Probability on CCDF, 3GPP Test Model 1, 64 DTCH.
- Adjacent Channel Power: -50 dBc @ 30 dBm, 5 MHz Channel Spacing
- Power Gain: 23.7 dB Min (@ f = 2140 MHz)
- · Excellent Phase Linearity and Group Delay Characteristics
- 0.2 dB Typical Gain Flatness
- Ideal for Feedforward Base Station Applications

MHPA21010

2110–2170 MHz 10 W, 23.7 dB RF HIGH POWER LDMOS AMPLIFIER



MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
DC Supply Voltage	V_{DD}	30	Vdc
RF Input Power (Single Carrier CW)	P _{in}	+20	dBm
Storage Temperature Range	T _{stg}	-40 to +100	°C
Operating Case Temperature Range	T _C	-20 to +100	°C
Quiescent Bias Current	I_{DQ}	750	mA

ELECTRICAL CHARACTERISTICS (V_{DD} = 28 Vdc, V_{BIAS} \cong 8 V Set for Supply Current of 550 mA, T_C = 25°C, 50 Ω System)

Characteristic		Symbol	Min	Тур	Max	Unit
Supply Current		I _{DD}	_	550	_	mA
Power Gain	(f = 2140 MHz)	Gp	23.7	25	_	dB
Gain Flatness	(f = 2110-2170 MHz)	G _F	_	0.2	0.6	dB
Power Output @ 1 dB Comp.	(f = 2140 MHz)	P1dB	_	41.5	_	dBm
Input VSWR	(f = 2110-2170 MHz)	VSWR _{in}	_	1.5:1	2:1	
Noise Figure	(f = 2140 MHz)	NF	_	_	10	dB
Adjacent Channel Power Rejection @ 30 5 MHz Channel Spacing	dBm Avg., 3.84 MHz BW,	ACPR	_	- 55	-50	dBc



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TYPICAL CHARACTERISTICS

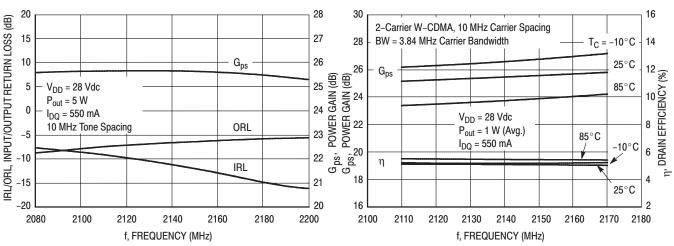


Figure 1. Two-Tone Power Gain, Input Return Loss and Output Return Loss versus Frequency

Figure 2. 2-Carrier W-CDMA Power Gain and Efficiency versus Frequency

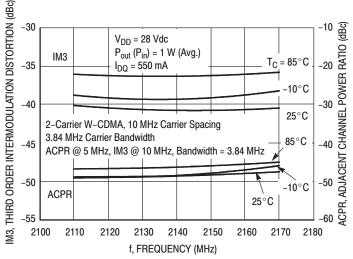


Figure 3. 2-Carrier W-CDMA IM3 and ACPR versus Frequency

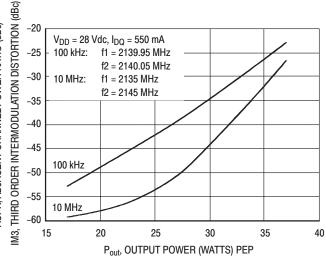


Figure 4. Two-Tone W-CDMA IM3 versus **Output Power**

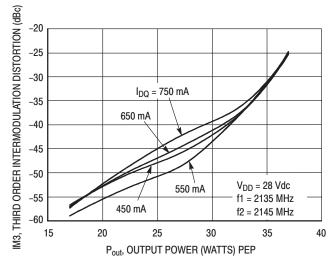


Figure 5. Third Order Intermodulation Distortion versus Output Power

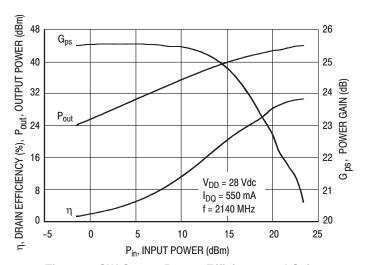


Figure 6. CW Output Power, Efficiency and Gain versus Input Power

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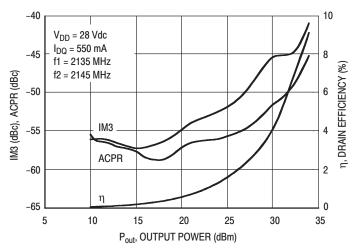
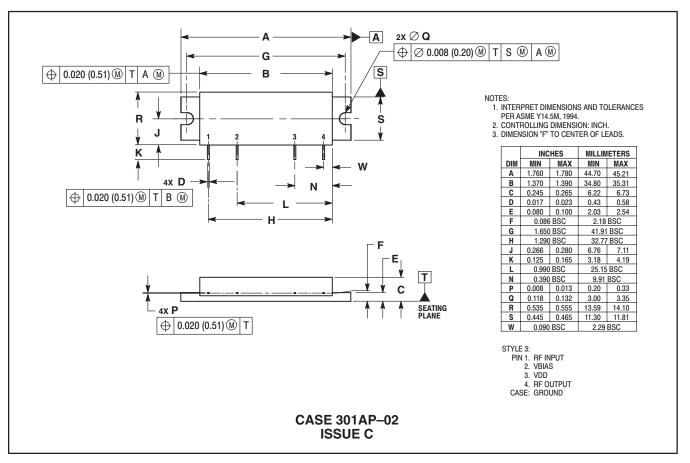


Figure 7. 2-Carrier W-CDMA ACPR, IM3 and Efficiency versus Output Power

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PACKAGE DIMENSIONS



NOTE: V_{DD} (Pin 3) should always be applied before V_{BIAS} (Pin 2).

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How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 1–303–675–2140 or 1–800–441–2447

JAPAN: Motorola Japan Ltd.; SPS, Technical Information Center, 3-20-1, Minami-Azabu. Minato-ku, Tokyo 106-8573 Japan. 81-3-3440-3569

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; Silicon Harbour Centre, 2 Dai King Street, Tai Po Industrial Estate, Tai Po, N.T. Hong Kong. 852–26668334

Technical Information Center: 1-800-521-6274

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